CNA1311K

Photo Interrupter

For contactless SW and object detection

Overview

CNA1311K is an ultraminiature, highly reliable transmissive photosensor in which a high efficiency GaAs infrared light emitting diode chip and a high sensitivity Si phototransistor chip are integrated in a double molded resin package.

Features

- Ultraminiature: 2.6 mm × 4.0 mm (height: 3.3 mm)
- Highly precise position detection: 0.05 mm
- Gap width: 1.0 mm

Absolute Maximum Ratings $T_a = 25^{\circ}C$ Parameter Symbol Rating Unit Power dissipation *1 75 P_D mW Input Forward current I_F 50 mА (Light emitting diode) Reverse voltage V_R 6 V Collector-emitter voltage V V_{CEO} 35 (Base open) Emitter-collector voltage Output V VECO 6 (Base open) (Photo transistor) 20 Collector current I_C mА Collector power dissipation *2 75 P_C mW Operating ambient temperature Topr -25 to +85 °C Storage temperature T_{stg} -40 to +100 °C

Note) *1: Input power derating ratio is 1.0 mW/°C at $T_a \ge 25^{\circ}C$

*2: Output power derating ratio is 1.0 mW/°C at $T_a \ge 25^{\circ}C$

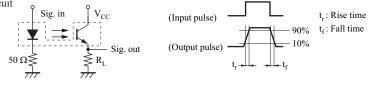
Electrical-Optical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter		Symbol	Conditions	Min	Тур	Max	Unit
Input characteristics	Reverse current	I _R	$V_R = 3 V$			10	μΑ
	Forward voltage	V _F	$I_F = 20 \text{ mA}$		1.2	1.4	V
Output characteristics	Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{CE} = 20 V$			100	nA
Transfer characteristics	Collector current	I _C	$V_{CE} = 5 V, I_F = 5 mA$	50		600	μΑ
	Collector-emitter saturation voltage	V _{CE(sat)}	$I_{\rm F} = 10 \text{ mA}, I_{\rm C} = 50 \mu \text{A}$			0.4	V
	Rise time *	t _r	$V_{CC} = 5 V, I_C = 0.1 mA,$ $R_L = 1000 \Omega$		50		μs
	Fall time *	t _f			50		μs

Note) 1. Input and output are practiced by electricity.

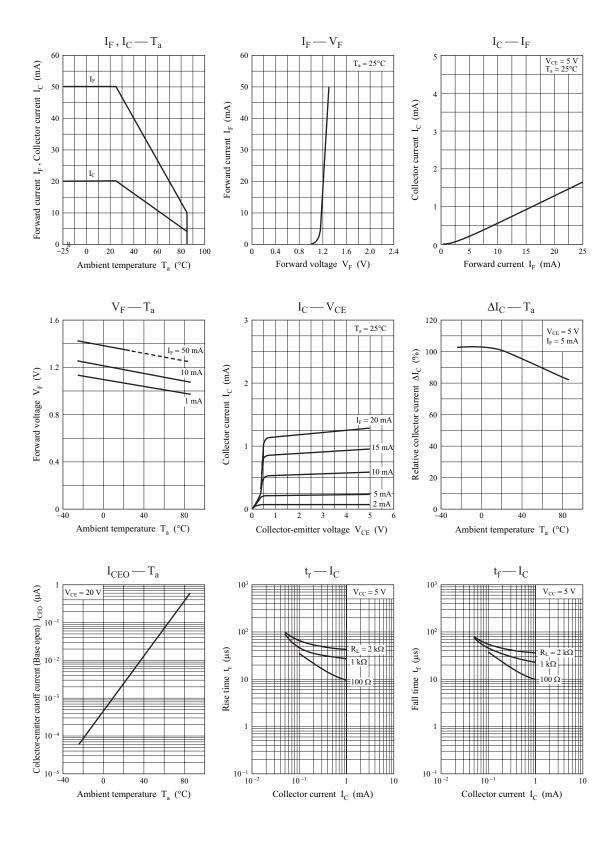
2. This device is designed by disregarding radiation.

3. *: Switching time measurement circuit

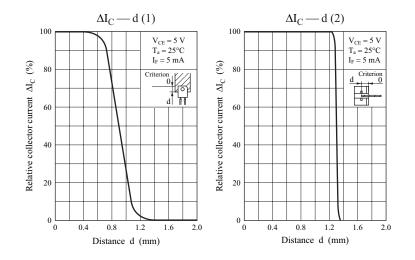


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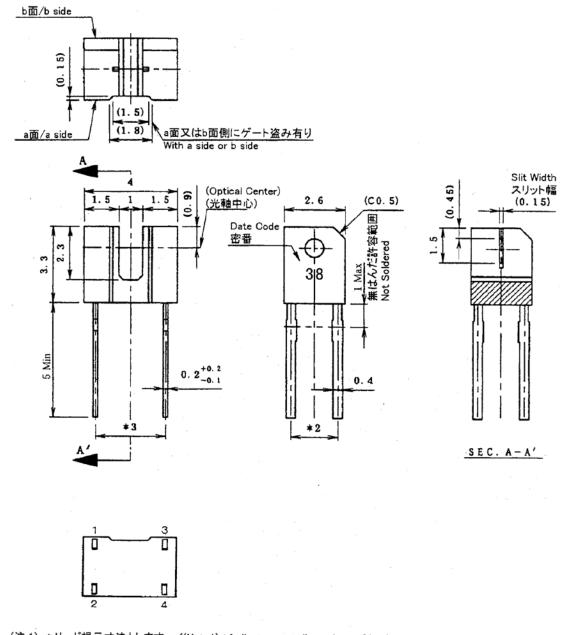


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Package (Unit: mm)

LSMSIN4S0002



(注 1) *リード根元寸法とします。/(Note1)* Indicates root dimensions of lead.
(注 2) 指示無き寸法公差は±0.2。/(Note2)Not appointment tolerance :±0.2.
(注 3) 密番は、目視又は顕微鏡に於いて解読できる事。
(Note3)What a date code sees an attention and can decode in a microscope.

- Pin name
 - 1: Anode
 - 2: Cathode
 - 3: Collector
 - 4: Emitter

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